

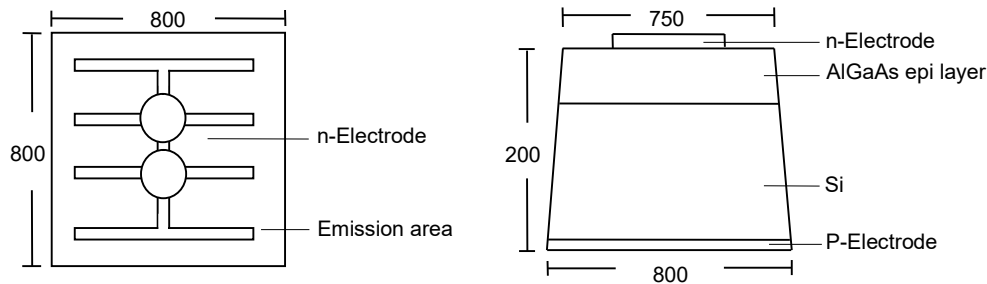
■ Features :

- Suitable for New Creative Products
- High Power
- High Performance
- Superior Thermal Stability

■ Typical Applications :

- Night Vision
- Camera
- Outdoor/Indoor applications

■ Outline Dimensions : (Unit: μm)



■ Physical Structure :

LED Chip dimension	Chip size	800 μm x 800 μm
	Thickness	200 \pm 25 μm
	Emission area	750 μm
	Bonding pad	125 \pm 10 μm
Electrode	Top: N (cathode)	Gold
	Backside: P (anode)	Gold

*C

■ Electro-Optical Characteristics : ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Forward Voltage	V_{FH}	$I_F = 350 \text{ mA}$	1.30	-	1.50	V
Reverse Current	I_R	$V_R = 10\text{V}$	-	-	1	μA
Radiant Power	P_o	$I_F = 350 \text{ mA}$	80	-	120	mW
Wavelength	λ_P	$I_F = 350 \text{ mA}$	940	-	950	Nm
Spectral width at half height	$\Delta\lambda$	$I_F = 350 \text{ mA}$	-	40	-	nm